

Silicon-Based Technology Corp.

Small-Signal Schottky Barrier Diodes

SBT103WS Series

SBT103WS series are Schottky Barrier Diodes fabricated by a series of proprietary Schottky barrier patents and technologies (SBT[®]) developed by Silicon-Based Technology Corporation, which exhibit high-performance characteristics for modern switching, conversion and protection applications with high speed and low power consumptions. The package types as described in this data sheet are set forth in routine production; other packages are available upon special orders.

■ Features and Advantages:

- Low forward voltage drop (V_F)
- Low reverse leakage current (I_R)
- Very small conduction power loss
- Very small switching power loss
- Very high switching speed
- Very high reliability

■ Electrical Characteristics : (@ $T_A=25^{\circ}\text{C}$ unless otherwise specified)

Characteristic		Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Reverse Breakdown Voltage (Note 2)	SBT103AWS	$V_{(BR)R}$	40	-	-	V	$I_R=100\mu\text{A}$
	SBT103BWS		30				
	SBT103CWS		20				
Forward Voltage Drop (Note 2)		V_{FM}	-	-	0.35 0.50	V	$I_F=20\text{mA}$ $I_F=200\text{mA}$
Peak Reverse Current (Note 2)	SBT103AWS	I_{RM}	-	-	5.0	μA	$V_R=30\text{V}$
	SBT103BWS						$V_R=20\text{V}$
	SBT103CWS						$V_R=10\text{V}$
Total Capacitance		C_T	-	28		pF	$V_R=0\text{V}$, $f=1.0\text{MHz}$
Reverse Recovery Time		t_{rr}	-	10	-	ns	$I_F=I_R=200\text{mA}$, $I_{rr}=0.1 \times I_R$, $R_L=100\Omega$



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**■ Maximum Ratings : (@T_A=25°C unless otherwise specified)**

Characteristic	Symbol	SBT103AWS	SBT103BWS	SBT103CWS	Unit
Peak Repetitive Reverse Voltage	V _{RRM}				
Working Peak Reverse Voltage	V _{RWM}	40	30	20	V
DC Blocking Voltage	V _R				
RMS Reverse Voltage	V _{R(RMS)}	28	21	14	V
Forward Continuous Current (Note 1)	I _{FM}	350			mA
Non-Repetitive Peak Forward Surge Current @t≤1.0s	I _{FSM}	1.5			A
Power Dissipation (Note 1)	P _d	200			mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R _{θJA}	625			°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +125			°C

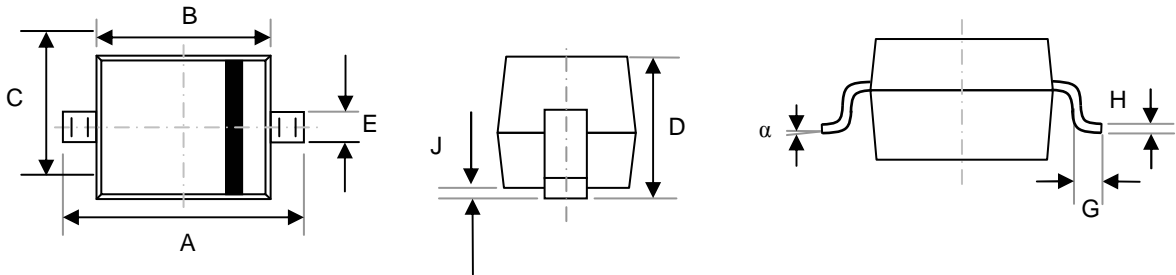
Notes: 1. Part mounted on FR4 PC Board with recommended pad layout, which can be found on our website at <http://www.sbt.com.tw>.

2. No purposefully added lead.

■ Package Data :

- Case: Molded Plastic Material (UL Flammability Classification 94V-0)
- Terminals: Solderable Plated Terminals (MIL-STD-202, Method 208)
- Lead Free Plating (Matte Tin Finish)
- Polarity: See device configurations below
- Approx. Weight: 0.004 grams.
- Package outline and dimensions (see below)

SOD-323



DIMENSIONS (MM)									
	A	B	C	D	E	G	H	J	α
Min.	2.30	1.60	1.20	1.05	0.25	0.20	0.10	0.05	0°
Max.	2.70	1.80	1.40	Typical	0.35	0.40	0.15	Typical	8°

■ Ordering Information (Note 3)

Part Number	Marking Code	Packaging Type	Shipping
			7" Tape & Real
SBT103AWS	SBTJAS	SOD-323	3K
SBT103BWS	SBTJBS	SOD-323	3K
SBT103CWS	SBTJCS	SOD-323	3K

Notes: 3. Website at <http://www.sbt.com.tw>

4. Bulk package in a box form is also available upon request.

5. Day code marking is YM, in which Y represents year (For example: 2005 is marked by 5);

M represents month in a year (For example: March is marked by C; November is marked by K).